

200 V, 1 A Silicon Germanium (SiGe) rectifier

28 July 2020

**Product data sheet** 

### 1. General description

Silicon Germanium (SiGe) rectifier encapsulated in a CFP3 (SOD123W) small and flat lead Surface-Mounted Device (SMD) plastic package.

### 2. Features and benefits

Features	Benefits				
<ul> <li>Low forward voltage and low Q<sub>rr</sub></li> <li>Extremely low leakage current</li> <li>Thermal stability up to 175 °C junction temperature</li> <li>Fast and smooth switching</li> <li>Low parasitic capacitance</li> <li>AEC-Q101 gualified</li> </ul>	<ul> <li>Excellent efficiency</li> <li>Extraordinary safe operating area</li> <li>Minimal impact on Electro-Magnetic Compatibility (EMC) allowing simplified certification</li> </ul>				

### 3. Applications

- High-efficiency power conversion
  - Automotive LED lighting
  - Engine control unit
  - Server power supply
  - Base station power supply
- Reverse polarity protection
- OR-ing

### 4. Quick reference data

Table 1. Qui	ck reference data						
Symbol	Parameter	Conditions		Min	Тур	Мах	Unit
I <sub>F(AV)</sub>	average forward current	δ = 0.5; square wave; f = 20 kHz; T <sub>sp</sub> ≤ 167 °C		-	-	1	A
V <sub>R</sub>	reverse voltage	T <sub>j</sub> = 25 °C		-	-	200	V
V <sub>F</sub>	forward voltage	I <sub>F</sub> = 1 A; T <sub>j</sub> = 25 °C; pulsed	[1]	-	805	880	mV
I <sub>R</sub>	reverse current	V <sub>R</sub> = 200 V; T <sub>j</sub> = 25 °C; pulsed	[1]	-	0.2	30	nA
		V <sub>R</sub> = 200 V; T <sub>j</sub> = 150 °C; pulsed	[1]	-	15	150	μA

[1] Very short pulse, in order to maintain a stable junction temperature.

# nexperia

#### 5. Pinning information

Table 2. P	Table 2. Pinning information							
Pin	Symbol	Description	Simplified outline	Graphic symbol				
1	К	cathode						
2	A	anode						
			CFP3 (SOD123W)	006aab040				

### 6. Ordering information

Table 3. Ordering information								
Type number	Package	age						
	Name	Description	Version					
PMEG200G10ELR		plastic, surface mounted package; 2 terminals; 2.6 mm x 1.7 mm x 1 mm body	SOD123W					

#### 7. Marking

Table 4. Marking codes	
Type number	Marking code
PMEG200G10ELR	LJ

#### 8. Limiting values

#### Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Attention: Stress above one of these maximum values may cause irreversible damage to the device.

Symbol	Parameter	Conditions		Min	Max	Unit
V <sub>R</sub>	reverse voltage	T <sub>j</sub> = 25 °C		-	200	V
I <sub>F</sub>	forward current	δ = 1; T <sub>sp</sub> ≤ 164 °C		-	1.4	А
I <sub>F(AV)</sub>	average forward current	δ = 0.5; square wave; f = 20 kHz; T <sub>sp</sub> ≤ 167 °C		-	1	A
I <sub>FSM</sub>	non-repetitive peak forward current	$t_p$ = 8.3 ms; half sine wave; $T_{j(init)}$ = 25 °C		-	40	A
P <sub>tot</sub>	total power dissipation	T <sub>amb</sub> ≤ 25 °C	[1]	-	0.68	W
			[2]	-	1.15	W
Tj	junction temperature			-	175	°C
T <sub>amb</sub>	ambient temperature			-55	175	°C
T <sub>stg</sub>	storage temperature			-65	175	°C

[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.

[2] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for cathode 1 cm<sup>2</sup>.

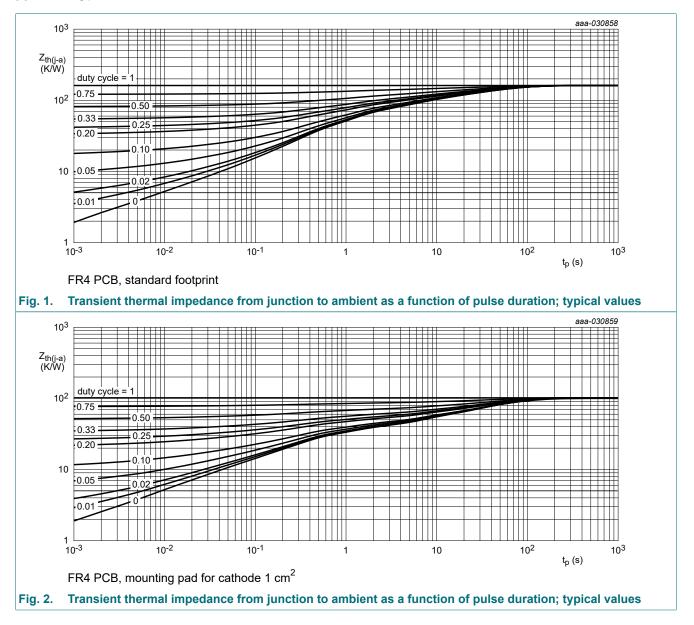
### 9. Thermal characteristics

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
R <sub>th(j-a)</sub> thermal resistance from	in free air	[1]	-	-	220	K/W	
	junction to ambient		[2]	-	-	130	K/W
R <sub>th(j-sp)</sub>	thermal resistance from junction to solder point		[3]	-	-	18	K/W

[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

[2] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for cathode 1 cm<sup>2</sup>.

[3] Soldering point of cathode tab.



### **10. Characteristics**

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
V <sub>(BR)R</sub>	reverse breakdown voltage	$I_R$ = 1 mA; pulsed; $T_j$ = 25 °C	[1]	200	-	-	V
V <sub>F</sub>	forward voltage	I <sub>F</sub> = 0.1 A; T <sub>j</sub> = 25 °C; pulsed	[1]	-	665	740	mV
		I <sub>F</sub> = 0.5 A; T <sub>j</sub> = 25 °C; pulsed	[1]	-	760	840	mV
		I <sub>F</sub> = 0.7 A; T <sub>j</sub> = 25 °C; pulsed	[1]	-	780	860	mV
		I <sub>F</sub> = 1 A; T <sub>j</sub> = 25 °C; pulsed	[1]	-	805	880	mV
		$I_F = 1 \text{ A}; T_j = -40 \text{ °C}; \text{ pulsed}$	[1]	-	890	980	mV
		I <sub>F</sub> = 1 A; T <sub>j</sub> = 125 °C; pulsed	[1]	-	660	760	mV
I <sub>R</sub> reverse	reverse current	$V_R$ = 200 V; $T_j$ = 25 °C; pulsed	[1]	-	0.2	30	nA
		$V_R$ = 200 V; $T_j$ = 125 °C; pulsed	[1]	-	2.5	25	μA
		$V_R$ = 200 V; $T_j$ = 150 °C; pulsed	[1]	-	15	150	μA
C <sub>d</sub>	diode capacitance	V <sub>R</sub> = 1 V; f = 1 MHz; T <sub>j</sub> = 25 °C		-	29	-	pF
		V <sub>R</sub> = 10 V; f = 1 MHz; T <sub>j</sub> = 25 °C		-	12	-	pF
t <sub>rr</sub>	reverse recovery time step recovery	$I_F = 0.5 \text{ A}; I_R = 1 \text{ A}; I_{R(meas)} = 0.25 \text{ A}; T_j = 25 \text{ °C}$		-	17	-	ns
	reverse recovery time ramp recovery	dI <sub>F</sub> /dt = 100 A/µs; I <sub>F</sub> = 1 A; V <sub>R</sub> = 30 V; T <sub>j</sub> = 25 °C		-	34	-	ns
I <sub>RM</sub>	peak reverse recovery current			-	1	-	A
Q <sub>rr</sub>	reverse recovery charge			-	19	-	nC
V <sub>FRM</sub>	peak forward recovery voltage	I <sub>F</sub> = 0.5 A; dI <sub>F</sub> /dt = 20 A/μs; T <sub>j</sub> = 25 °C		-	885	-	mV

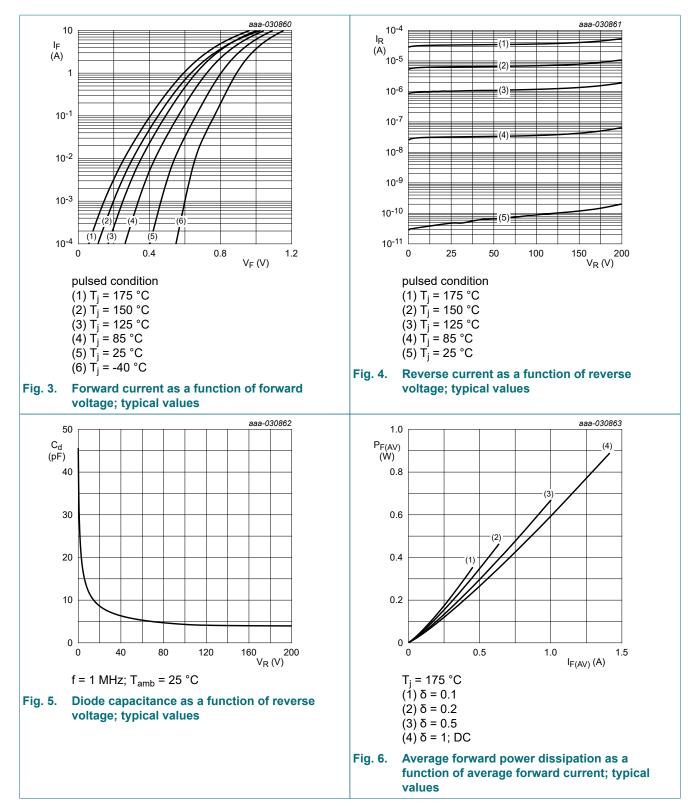
[1] Very short pulse, in order to maintain a stable junction temperature.

PMEG200G10ELR

#### Nexperia

### PMEG200G10ELR

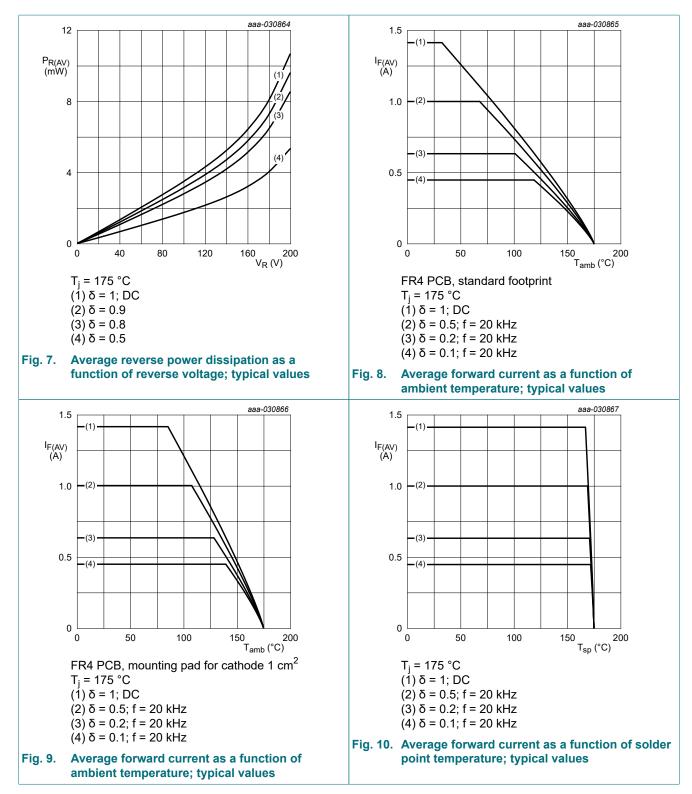
#### 200 V, 1 A Silicon Germanium (SiGe) rectifier



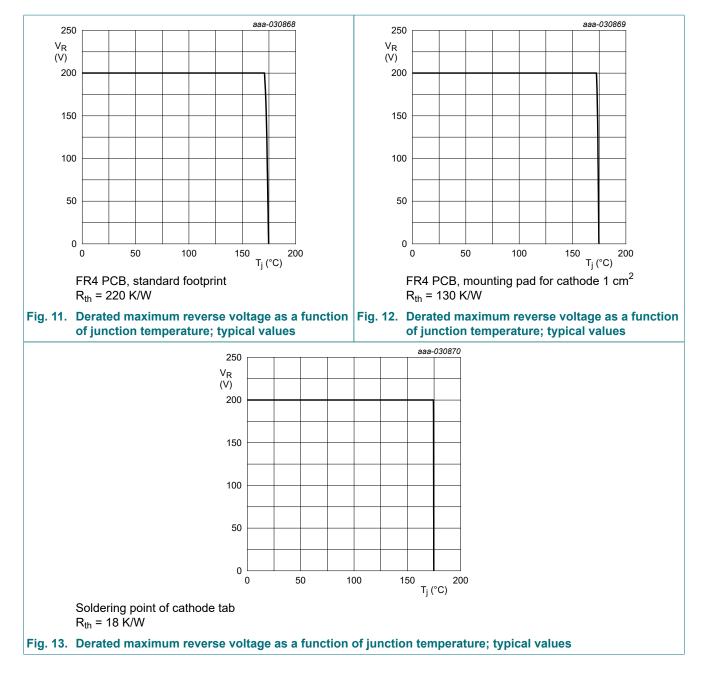
PMEG200G10ELR

5/14

#### 200 V, 1 A Silicon Germanium (SiGe) rectifier

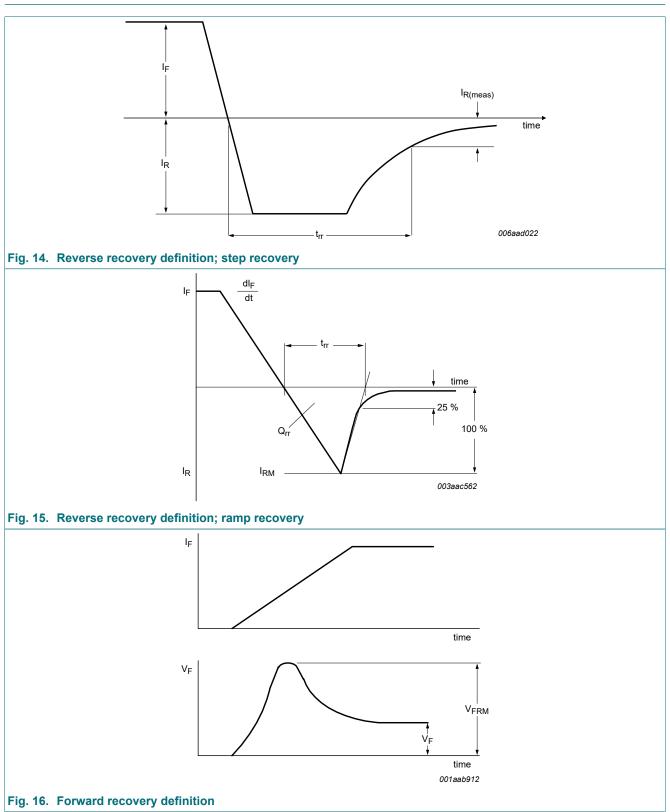


#### 200 V, 1 A Silicon Germanium (SiGe) rectifier

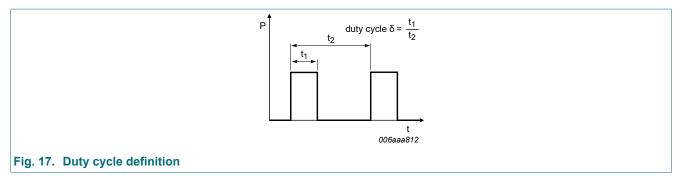


#### 200 V, 1 A Silicon Germanium (SiGe) rectifier

### **11. Test information**



#### 200 V, 1 A Silicon Germanium (SiGe) rectifier



The current ratings for the typical waveforms are calculated according to the equations:

 $I_{F(AV)}=I_M \times \delta$  with  $I_M$  defined as peak current

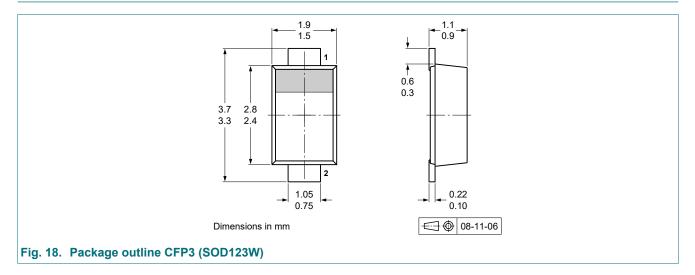
 $I_{RMS}=I_{F(AV)}$  at DC, and  $I_{RMS}=I_M \times \sqrt{\delta}$ 

with  $\mathsf{I}_{\mathsf{RMS}}$  defined as RMS current.

#### **Quality information**

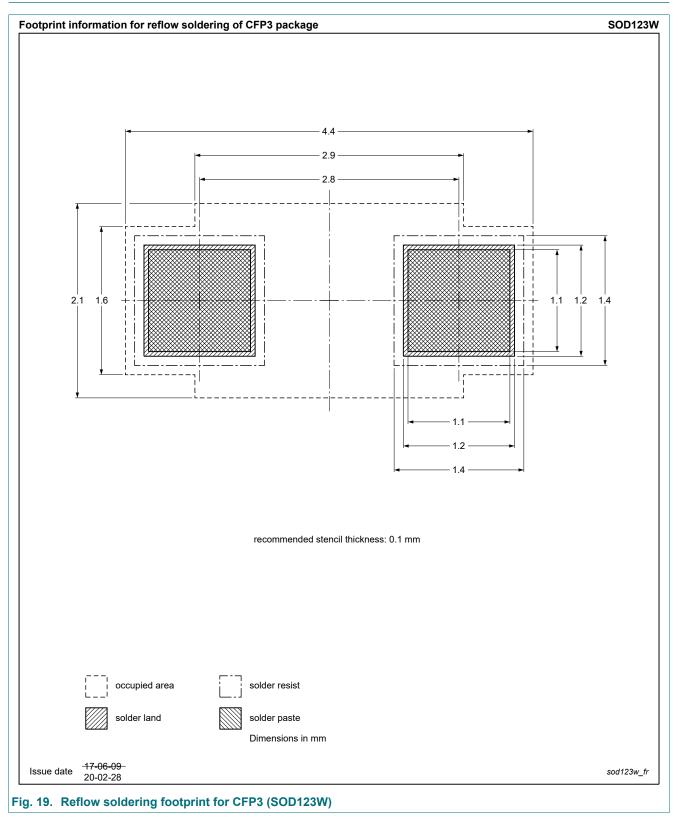
This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard Q101 - Stress test qualification for discrete semiconductors, and is suitable for use in automotive applications.

#### 12. Package outline

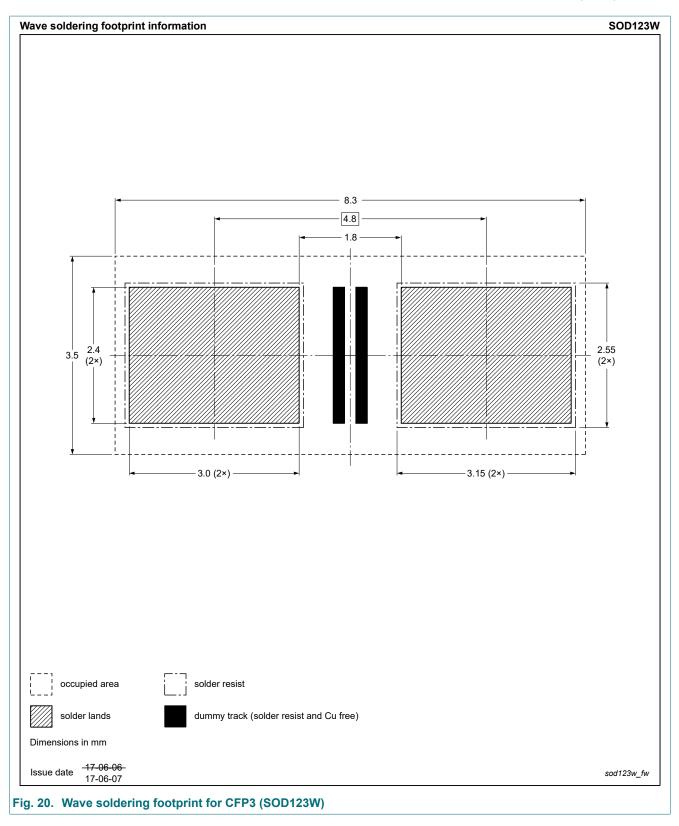


#### 200 V, 1 A Silicon Germanium (SiGe) rectifier

### 13. Soldering



#### 200 V, 1 A Silicon Germanium (SiGe) rectifier



#### 14. Mounting

This device is sensitive to Electro Static Discharge (ESD). Observe precautions for handling electrostatic sensitive devices. Such precautions are described in the ANSI/ESD S20.20, IEC/ST 61340-5, JESD625-A or equivalent standards.

PMEG200G10ELR

© Nexperia B.V. 2020. All rights reserved

### **15. Revision history**

Table 8. Revision history				
Data sheet ID	Release date	Data sheet status	Change notice	Supersedes
PMEG200G10ELR v.1	20200728	Product data sheet	-	-

PMEG200G10ELR

### 16. Legal information

#### Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

 Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

[3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the internet at <u>https://www.nexperia.com</u>.

#### **Definitions**

**Draft** — The document is a draft version only. The content is still under internal review and subject to formal approval, which may result in modifications or additions. Nexperia does not give any representations or warranties as to the accuracy or completeness of information included herein and shall have no liability for the consequences of use of such information.

Short data sheet — A short data sheet is an extract from a full data sheet with the same product type number(s) and title. A short data sheet is intended for quick reference only and should not be relied upon to contain detailed and full information. For detailed and full information see the relevant full data sheet, which is available on request via the local Nexperia sales office. In case of any inconsistency or conflict with the short data sheet, the full data sheet shall prevail.

**Product specification** — The information and data provided in a Product data sheet shall define the specification of the product as agreed between Nexperia and its customer, unless Nexperia and customer have explicitly agreed otherwise in writing. In no event however, shall an agreement be valid in which the Nexperia product is deemed to offer functions and qualities beyond those described in the Product data sheet.

#### **Disclaimers**

Limited warranty and liability — Information in this document is believed to be accurate and reliable. However, Nexperia does not give any representations or warranties, expressed or implied, as to the accuracy or completeness of such information and shall have no liability for the consequences of use of such information. Nexperia takes no responsibility for the content in this document if provided by an information source outside of Nexperia.

In no event shall Nexperia be liable for any indirect, incidental, punitive, special or consequential damages (including - without limitation - lost profits, lost savings, business interruption, costs related to the removal or replacement of any products or rework charges) whether or not such damages are based on tort (including negligence), warranty, breach of contract or any other legal theory.

Notwithstanding any damages that customer might incur for any reason whatsoever, Nexperia's aggregate and cumulative liability towards customer for the products described herein shall be limited in accordance with the Terms and conditions of commercial sale of Nexperia.

**Right to make changes** — Nexperia reserves the right to make changes to information published in this document, including without limitation specifications and product descriptions, at any time and without notice. This document supersedes and replaces all information supplied prior to the publication hereof.

Suitability for use in automotive applications — This Nexperia product has been qualified for use in automotive applications. Unless otherwise agreed in writing, the product is not designed, authorized or warranted to be suitable for use in life support, life-critical or safety-critical systems or

#### 200 V, 1 A Silicon Germanium (SiGe) rectifier

equipment, nor in applications where failure or malfunction of an Nexperia product can reasonably be expected to result in personal injury, death or severe property or environmental damage. Nexperia and its suppliers accept no liability for inclusion and/or use of Nexperia products in such equipment or applications and therefore such inclusion and/or use is at the customer's own risk.

**Quick reference data** — The Quick reference data is an extract of the product data given in the Limiting values and Characteristics sections of this document, and as such is not complete, exhaustive or legally binding.

**Applications** — Applications that are described herein for any of these products are for illustrative purposes only. Nexperia makes no representation or warranty that such applications will be suitable for the specified use without further testing or modification.

Customers are responsible for the design and operation of their applications and products using Nexperia products, and Nexperia accepts no liability for any assistance with applications or customer product design. It is customer's sole responsibility to determine whether the Nexperia product is suitable and fit for the customer's applications and products planned, as well as for the planned application and use of customer's third party customer(s). Customers should provide appropriate design and operating safeguards to minimize the risks associated with their applications and products.

Nexperia does not accept any liability related to any default, damage, costs or problem which is based on any weakness or default in the customer's applications or products, or the application or use by customer's third party customer(s). Customer is responsible for doing all necessary testing for the customer's applications and products using Nexperia products in order to avoid a default of the applications and the products or of the application or use by customer's third party customer(s). Nexperia does not accept any liability in this respect.

Limiting values — Stress above one or more limiting values (as defined in the Absolute Maximum Ratings System of IEC 60134) will cause permanent damage to the device. Limiting values are stress ratings only and (proper) operation of the device at these or any other conditions above those given in the Recommended operating conditions section (if present) or the Characteristics sections of this document is not warranted. Constant or repeated exposure to limiting values will permanently and irreversibly affect the quality and reliability of the device.

Terms and conditions of commercial sale — Nexperia products are sold subject to the general terms and conditions of commercial sale, as published at <u>http://www.nexperia.com/profile/terms</u>, unless otherwise agreed in a valid written individual agreement. In case an individual agreement is concluded only the terms and conditions of the respective agreement shall apply. Nexperia hereby expressly objects to applying the customer's general terms and conditions with regard to the purchase of Nexperia products by customer.

No offer to sell or license — Nothing in this document may be interpreted or construed as an offer to sell products that is open for acceptance or the grant, conveyance or implication of any license under any copyrights, patents or other industrial or intellectual property rights.

**Export control** — This document as well as the item(s) described herein may be subject to export control regulations. Export might require a prior authorization from competent authorities.

**Translations** — A non-English (translated) version of a document is for reference only. The English version shall prevail in case of any discrepancy between the translated and English versions.

#### Trademarks

Notice: All referenced brands, product names, service names and trademarks are the property of their respective owners.

### Contents

1. General description	1
2. Features and benefits	1
3. Applications	1
4. Quick reference data	1
5. Pinning information	2
6. Ordering information	2
7. Marking	2
8. Limiting values	2
9. Thermal characteristics	3
10. Characteristics	4
11. Test information	8
12. Package outline	9
13. Soldering	10
14. Mounting	11
15. Revision history	12
16. Legal information	13

© Nexperia B.V. 2020. All rights reserved

For more information, please visit: http://www.nexperia.com For sales office addresses, please send an email to: salesaddresses@nexperia.com Date of release: 28 July 2020

PMEG200G10ELR

### **X-ON Electronics**

Largest Supplier of Electrical and Electronic Components

Click to view similar products for Diodes - General Purpose, Power, Switching category:

Click to view products by Nexperia manufacturer:

Other Similar products are found below :

RD0306T-H BAV17-TR BAV19-TR 1N3611 NTE156A NTE525 NTE571 NTE574 NTE5804 NTE5806 NTE6244 1SS181-TP 1SS193,LF 1SS400CST2RA SDAA13 SHN2D02FUTW1TIG LS4151GS08 1N4449 1N456A 1N4934-E3/73 1N914B 1N914BTR BAV199-TP BAW56DWQ-7-F BAW75-TAP MM230L-CAA IDW40E65D1 JAN1N3600 LL4151-GS18 053684A SMMSD4148T3G 707803H NSVDAN222T1G SP000010217 CDSZC01100-HF BAV199E6433HTMA1 BAV70M3T5G SMBT2001T1G NTE5801 NTE5800 NTE5808 NTE6240 NTE6248 BAS28-7 BAW56HDW-13 BAS28 TR VS-HFA04SD60STR-M3 NSVM1MA152WKT1G BAV99TQ-13-F BAS21DWA-7